

**61096**

**GENERAL PURPOSE (NPN) TRANSISTOR  
(2N2222A)**



**OPTOELECTRONIC PRODUCTS  
DIVISION**

**Features:**

- Hermetically sealed
- Rugged package-able to withstand high acceleration load
- TO-18 package
- MIL-PRF-19500 screening available

**Applications:**

- Analog Switches
- Signal Conditioning
- Small Signal Amplifiers
- High Density Packaging

**DESCRIPTION**

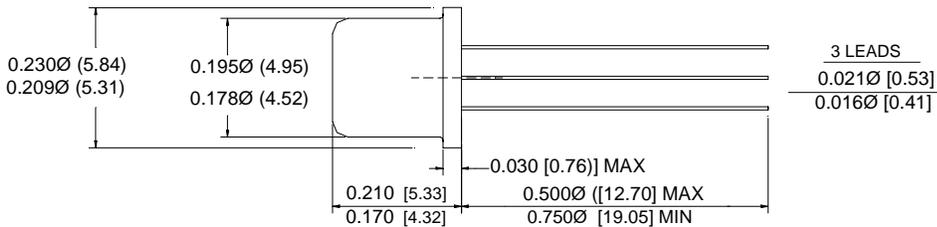
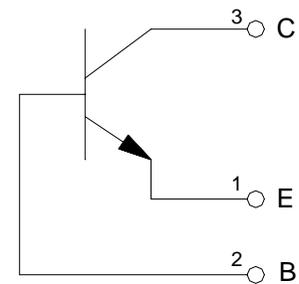
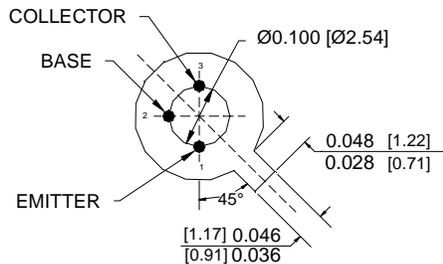
The **61096** is a hermetically sealed general purpose switching transistor in a TO-18 package. This rugged package is able to withstand high acceleration loads and is ideal for designs where durability and device weight are important requirements. This device is available custom binned to customer specifications or screened to MIL-PRF-19500.

**ABSOLUTE MAXIMUM RATINGS**

|   |                 |
|---|-----------------|
| Collector-Base Voltage .....  | 75V             |
| Collector-Emitter Voltage .....   | 50V             |
| Emitter-Collector Voltage .....   | 6V              |
| Continuous Collector Current.....   | 800mA           |
| Power Dissipation (Derate at the rate of 3.33 mW/°C above 25°C) .....                   | 500mW           |
| Maximum Junction Temperature .....  | +200°C          |
| Operating Temperature (See part selection guide for actual operating temperature) ..... | -65°C to +200°C |
| Storage Temperature .....   | -65°C to +200°C |
| Lead Soldering Temperature (vapor phase reflow for 30 seconds) .....                    | 215°C           |

**Package Dimensions**

**Schematic Diagram**



DIMENSIONS ARE IN INCHES (MILLIMETERS)

## OPTICAL/ELECTRICAL CHARACTERISTICS

T<sub>A</sub> = 25°C unless otherwise specified.

| PARAMETER                            | SYMBOL                         | MIN | MAX  | UNITS | TEST CONDITIONS   | NOTE |
|--------------------------------------|--------------------------------|-----|------|-------|---|------|
| Collector-Base Breakdown Voltage     | BV <sub>CBO</sub>              | 75  |      | V     | I <sub>C</sub> = 10μA, I <sub>E</sub> = 0                         |      |
| Collector-Emitter Breakdown Voltage  | BV <sub>CEO</sub>              | 50  |      | V     | I <sub>C</sub> = 10mA, I <sub>B</sub> = 0μA                       |      |
| Emitter-Base Breakdown Voltage       | BV <sub>EBO</sub>              | 6   |      | V     | I <sub>C</sub> = 0, I <sub>E</sub> = 10μA                         |      |
| Collector-Base Cutoff Current        | I <sub>CBO</sub>               |     | 10   | nA    | V <sub>CB</sub> = 60V, I <sub>E</sub> = 0                         |      |
|                                      |                                |     | 10   | μA    | V <sub>CB</sub> = 60V, I <sub>E</sub> = 0, T <sub>A</sub> = 150°C |      |
| Collector-Emitter Cutoff Current     | I <sub>CES</sub>               |     | 50   | nA    | V <sub>CE</sub> = 50V   |      |
| Emitter-Base Cutoff Current          | I <sub>EBO</sub>               |     | 10   | nA    | V <sub>EB</sub> = 4.0V, I <sub>C</sub> = 0                        |      |
| Forward-Current Transfer Ratio       | h <sub>fe1</sub>               | 50  |      | -     | V <sub>CE</sub> = 10V, I <sub>C</sub> = 0.1mA                     |      |
|                                      |                                | 75  | 325  | -     | V <sub>CE</sub> = 10V, I <sub>C</sub> = 1mA                       |      |
|                                      | Forward-Current Transfer Ratio | 100 |      | -     | V <sub>CE</sub> = 10V, I <sub>C</sub> = 10mA                      |      |
|                                      |                                | 100 | 300  | -     | V <sub>CE</sub> = 10V, I <sub>C</sub> = 150mA                     | 1    |
|                                      |                                | 30  |      | -     | V <sub>CE</sub> = 10V, I <sub>C</sub> = 500mA                     | 1    |
|                                      |                                | 35  |      | -     | V <sub>CE</sub> = 10V, I <sub>C</sub> = 1mA @ -55°C               |      |
| Collector-Emitter Saturation Voltage | V <sub>CE(SAT)</sub>           |     | 0.30 | V     | I <sub>C</sub> = 150mA, I <sub>B</sub> = 15mA                     | 1    |
|                                      |                                |     | 1.0  | V     | I <sub>C</sub> = 500, I <sub>B</sub> = 50mA                       | 1    |
| Base-Emitter Saturation Voltage      | V <sub>BE(SAT)</sub>           | 0.6 | 1.20 | V     | I <sub>C</sub> = 150mA, I <sub>B</sub> = 15mA                     | 1    |
|                                      |                                |     | 2.0  | V     | I <sub>C</sub> = 500mA, I <sub>E</sub> = 50mA                     | 1    |

## SMALL-SIGNAL CHARACTERISTICS

|   |                   |     |     |    |  |  |
|---|-------------------|-----|-----|----|--|--|
| Small Signal Forward Current Transfer Ratio | h <sub>re</sub>   | 50  |     | -  | V <sub>CE</sub> = 10V, I <sub>C</sub> = 1mA, f = 1kHz                                      |  |
| Small Signal Forward Current Transfer Ratio | h <sub>re</sub>   | 2.5 |     | -  | V <sub>CE</sub> = 20V, I <sub>C</sub> = 20mA,<br>f = 100kHz                                |  |
| Open Circuit Output Capacitance             | C <sub>OBO</sub>  |     | 8   | pF | V <sub>CB</sub> = 10V, 100kHz, ≤ f ≤ 1 MHz   |  |
| Input Capacitance (Output Open Capacitance) | C <sub>I BO</sub> |     | 25  | pF | V <sub>EB</sub> = 0.5 V, 100kHz, ≤ f ≤ 1 MHz   |  |
| Turn-On Time                                | t <sub>on</sub>   |     | 35  | ns | V <sub>CC</sub> = 30V, I <sub>C</sub> = 150mA,<br>I <sub>B1</sub> = 15mA                   |  |
| Turn-Off Time                               | t <sub>off</sub>  |     | 300 | ns | V <sub>CC</sub> = 30V, I <sub>C</sub> = 150mA,<br>I <sub>B1</sub> = I <sub>B2</sub> = 15mA |  |

## NOTES:

- Pulse width ≤ 300μs, duty cycle ≤ 2.0%.

## RECOMMENDED OPERATING CONDITIONS:

| PARAMETER                      | SYMBOL          | MIN | MAX | UNITS |
|--------------------------------|-----------------|-----|-----|-------|
| Bias Voltage-Collector/Emitter | I <sub>C</sub>  | 10  | 150 | mA    |
| Collector-Emitter Voltage      | V <sub>CE</sub> | 5   | 20  | V     |

## SELECTION GUIDE

| PART NUMBER | PART DESCRIPTION                               |
|-------------|--|
| 61096-001   | 2N2222A PNP transistor, commercial version     |
| 61096-002   | 2N2222A PNP transistor, JAN level screening    |
| 61096-101   | 2N2222A PNP transistor, JANTX level screening  |
| 61096-102   | 2N2222A PNP transistor, JANTXV level screening |
| 61096-103   | 2N2222A PNP transistor, JANS level screening   |